

## HITANO ENTERPRISE CORP.

#### FR601G THRU FR607G

# TECHNICAL SPECIFICATIONS OF FAST RECOVERY GLASS PASSIVATED RECTIFIER VOLTAGE RANGE - 50 to 1000 Volts CURRENT - 6.0 Amperes

#### **FEATURES**

- \* High reliability
- \* Low leakage
- \* Low forward voltage drop
- \* High current capability
- \* High switching capability
- \* Glass passivated junction

### MECHANICAL DATA

\* Case: Molded plastic

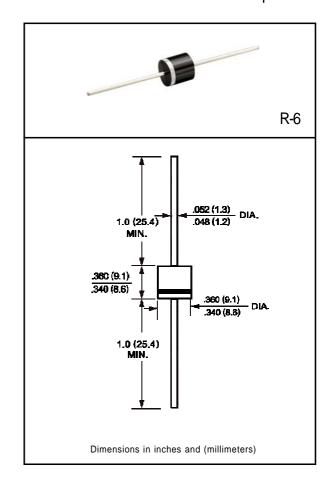
\* Epoxy: UL 94V-0 rate flame retardant\* Lead: MIL-STD-202E, Method 208 guaranteed

\* Polarity: Color band denotes cathode end

\* Mounting position: Any\* Weight: 2.08 grams

#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at  $25\,^{\circ}\text{C}$  ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.



	SYMBOL	FR601G	FR602G	FR603G	FR604G	FR605G	FR606G	FR607G	UNITS
Maximum Recurrent Peak Reverse Voltage	Vrrm	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	VRMS	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	VDC	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Current at TA = 55°C	lo	6.0							Amps
Peak Forward Surge Current 8.3 ms single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	300							Amps
Maximum Instantaneous Forward Voltage at 6.0A DC	VF	1.3						Volts	
Maximum DC Reverse Current at Rated DC Blocking Voltage TA = 25°C	la la	5.0							uAmps
Maximum Full Load Reverse Current Average, Full Cycle .375*(9.5mm) lead length at T ∟ = 55°C	IR IR	100							uAmps
Maximum Reverse Recovery Time (Note 1)	trr		1	50		250	5	600	nSec
Typical Junction Capacitance (Note 2)	Cı	50						pF	
Operating and Storage Temperature Range	TJ, TSTG	-65 to + 150							٥C

NOTES: 1. Test Conditions: IF = 0.5A, IR = 1.0A, IRR = 0.25A

2. Measured at 1  $\ensuremath{\text{MHz}}$  and applied reverse voltage of 4.0 volts

#### RATING AND CHARACTERISTIC CURVES (FR601G THRU FR607G)

FIG. 1 - TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC 10 Ω NON[NDUCT]VE NONINDUCTIVE +0.5A D.U.T 0 (+) PULSE 25 Vdc -0.25A GENERATOR (approx) (NOTE 2) (-)1Ω OSCILLOSCOPE (+)NON-(NOTE 1) NDUCTIVE -1.0A

SET TIME BASE FOR NOTES: 1 Rise Time = 7ns max, Input Impedance = 50/100 ns/cm 1 megohm. 22 pF.

FIG. 2 - TYPICAL FORWARD CURRENT DERATING CURVE

50 ohms.

2. Rise Time = 10ns max. Source Impedance =

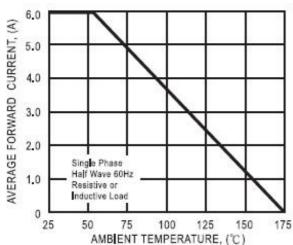


FIG. 3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

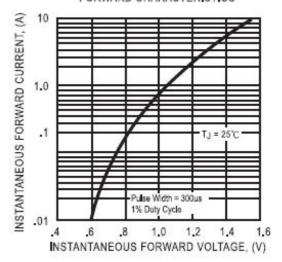


FIG. 4 - TYPICAL JUNCTION CAPACITANCE

